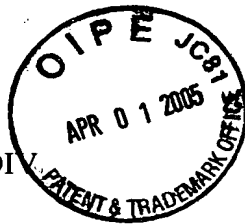


DOCKET NO: 245469US-2 DIV 1



IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :
TADASHI IGUCHI, ET AL. : EXAMINER: CHEN, J. S. J.
SERIAL NO: 10/716,556 :
FILED: NOVEMBER 20, 2003 : GROUP ART UNIT: 2813
FOR: NONVOLATILE :
SEMICONDUCTOR MEMORY DEVICE
AND ITS MANUFACTURING METHOD

AMENDMENT

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action of January 11, 2005, please amend the above-identified application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 3 of this paper.

Remarks/Arguments begin on page 6 of this paper.